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In The United States Patent and Trademark Office

Application Number 10/750588
Application Filed 31 December 2003
Applicants: Thomas J. Wells, Robert Scott Elliott
Title: Micro-Electrometer
Examiner / GAU: Vincent Q. Nguyen / 2858

Amendment A

Commissioner for Patents
Washington, District of Columbia 20231

Sir:

In response to the Office Letter mailed 10 March 2005, please amend the above application as follows:

Specification:

Page 2, last sentence, replace with the following sentence:

Leakage currents of 10 sup-10 amps and input resistances of 10 sup 11 ohms are typical for diode gate protected MOSFETs.

Page 7, last sentence of DESCRIPTION OF THE INVENTION, replace with the following sentence:

Screen resistor 33 connects to the screen grid (second and fourth grids) terminal of tube 37'.